# ESD Protection Diode Array

Low Capacitance ESD Protection Diode for High Speed Data Line

# **ESD1014**

The ESD1014 surge protectionis designed to protect high speed data lines from ESD, EFT, and lightning.

### Features

- Low Capacitance (6 pF Maximum Between I/O Lines and GND)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body model and Class C (Exceeding 400 V) per Machine Model
- Protection for the Following IEC Standards: IEC 61000-4-2 (ESD) Level 4 - 30 kV (Contact)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb–Free Device

#### **Typical Applications**

- High Speed Communication Line Protection
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays
- T1/E1 and T3/E3
- 10/100/1000 Ethernet Protection
- Gigabit Ethernet Protection

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1)	P <sub>pk</sub>	450	W
Maximum Peak Pulse Current (Note 1)	I <sub>PP</sub>	30	A
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	ΤL	260	°C
Machine Model (MM) Human Body Model (HBM) IEC 61000-4-2 Contact (ESD)	ESD	0.4 16 30	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 8/20  $\mu$ s Waveform per Figure 2 (@ T<sub>A</sub> = 25°C).

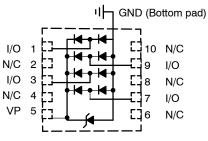


## **ON Semiconductor®**

www.onsemi.com

### LOW CAPACITANCE DIODE SURGE PROTECTION ARRAY

#### **PIN CONFIGURATION** AND SCHEMATIC





## MARKING DIAGRAM

UDFN10 CASE 517AN

А



= Specific Device Code 1014

/14	= Specific Device Coc
	= Assembly Location

= Year

Υ = Work Week W

= Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
ESD1014MUTAG	UDFN10 (Pb-Free)	3000 / Tape & Reel
SZESD1014MUTAG	UDFN10 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## ESD1014

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 1)			3.3	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> =1 mA, (Note 2)	5.0	5.3		V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3 V			5.0	μA
Clamping Voltage	V <sub>C</sub>	Pin 5 to GND, I <sub>PP</sub> = 1 A			6.2	V
Clamping Voltage	V <sub>C</sub>	Any I/O pin to GND I <sub>PP</sub> = 1 A I <sub>PP</sub> = 10 A I <sub>PP</sub> = 25 A			7.5 9.0 11	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8/20 μs Waveform per Figure 2			30	А
Junction Capacitance	CJ	$V_R$ = 0 V, f=1 MHz between I/O Pins and GND		3.8	5.0	pF
		V <sub>R</sub> = 0 V, f=1 MHz between I/O Pins		1.5	3.0	1

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified)

15

10

5

0

0

5

10

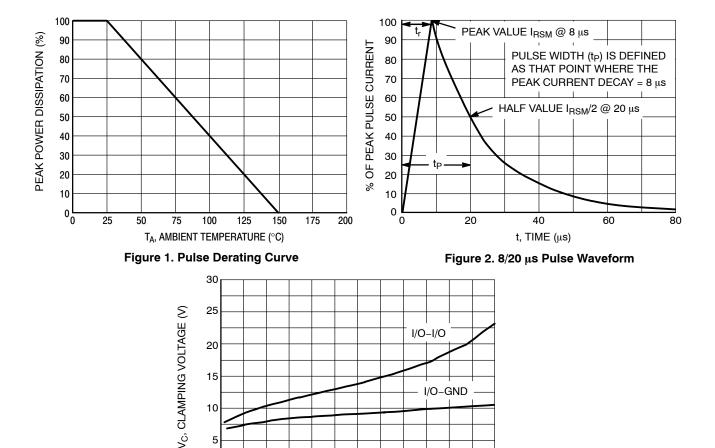
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater 1. than the DC or continuous peak operating voltage level.

2. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

#### **TYPICAL PERFORMANCE CURVES**

(T<sub>1</sub> = 25°C unless otherwise noted)



15

IPP, PEAK CURRENT (A) Figure 3. Clamping Voltage, 8/20 µs Waveform

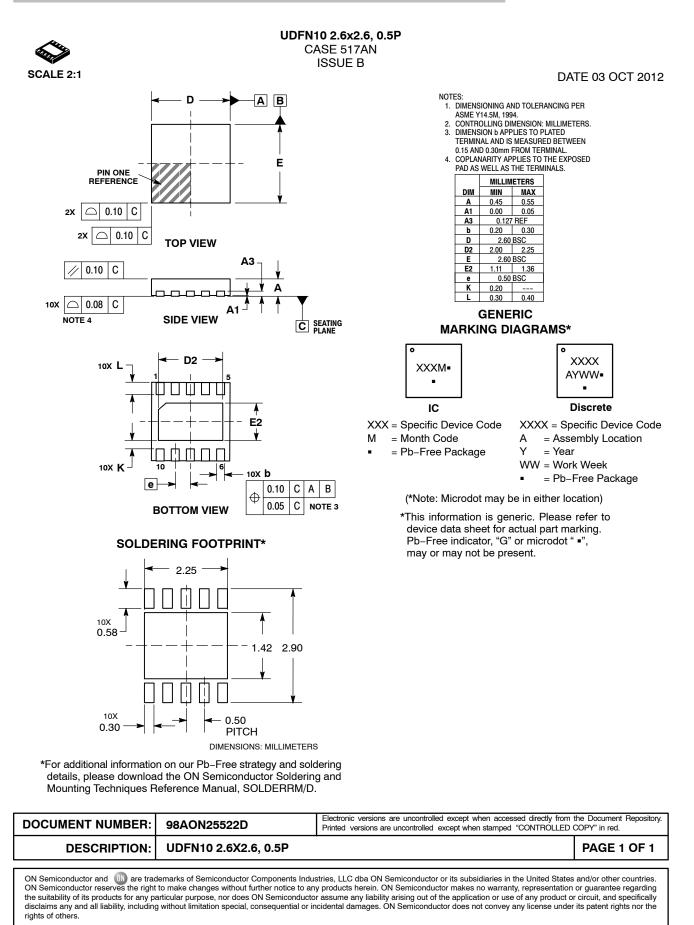
20

I/O-GND

25

30





onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for ESD Suppressors / TVS Diodes category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

60KS200C D12V0H1U2WS-7 D18V0L1B2LP-7B 82356050220 D5V0M5U6V-7 NTE4902 P4KE27CA P6KE11CA P6KE39CA-TP P6KE8.2A SA110CA SA60CA SA64CA SMBJ12CATR SMBJ8.0A SMLJ30CA-TP ESD101-B1-02ELS E6327 ESD112-B1-02EL E6327 ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF 3.0SMCJ33CA-F 3.0SMCJ36A-F HSPC16701B02TP D3V3Q1B2DLP3-7 D55V0M1B2WS-7 DESD5V0U1BL-7B DRTR5V0U4SL-7 SCM1293A-04SO ESD200-B1-CSP0201 E6327 ESD203-B1-02EL E6327 SM12-7 SMF8.0A-TP SMLJ45CA-TP CEN955 W/DATA 82350120560 82356240030 VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF CPDQC5V0-HF D1213A-01LP4-7B D1213A-02WL-7 ESDLIN1524BJ-HQ 5KP100A